The RF Line NPN Silicon RF Power Transistor

The MRF6403 is designed for 1.8 GHz Personal Communications Network (PCN) base station applications. It incorporates high value emitter ballast resistors, gold metallizations and offers a high degree of reliability and ruggedness.

- To be used in Class AB for PCN and Cellular Radio
- Specified 26 Volts, 1.88 GHz Characteristics

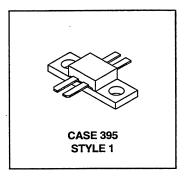
Output Power — 25 Watts

Gain - 6.5 dB Typ

Efficiency — 43% Typ

MRF6403

25 W, 1.88 GHz RF POWER TRANSISTOR NPN SILICON



MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	VCER	40	Vdc	
Collector-Base Voltage	V _{CBO}	45	Vdc	
Emitter-Base Voltage	V _{EBO}	3.5	Vdc	
Collector-Current — Continuous	lc	2.5	Adc	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	70 0.4	Watts W/°C	
Storage Temperature Range	T _{stg}	-65 to +150	°C	
Operating Junction Temperature	Tj	200	°C	

THERMAL CHARACTERISTICS

Characteristic		Max	Unit
Thermal Resistance, Junction to Case (1)	R ₀ JC	2.5	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (I _C = 10 mA, R _{BE} = 75 Ω)	V _(BR) CER	40		_	Vdc
Emitter-Base Breakdown Voltage (I _E = 5 mAdc)	V _{(BR)EBO}	3.5			Vdc
Collector-Base Breakdown Voltage (I _C = 10 mAdc)	V _(BR) CBO	45	_		Vdc
Collector-Emitter Leakage ($V_{CE} = 26 \text{ V}$, $R_{BE} = 75 \Omega$)	ICER	-		5	mA

⁽¹⁾ Thermal resistance is determined under specified RF operating condition.



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ELECTRICAL CHARACTERISTICS — continued ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS					
DC Current Gain (I _C = 0.2 Adc, V _{CE} = 20 Vdc)	hFE	30	_	120	_
DYNAMIC CHARACTERISTICS					
Output Capacitance (each side) (V _{CB} = 26 V, I _E = 0, f = 1 MHz)	C _{ob} .		15	_	pF
FUNCTIONAL TESTS					
Common-Emitter Amplifier Power Gain (V _{CC} = 26 V, P _{out} = 25 W, I _{CQ} = 200 mA, f = 1.88 GHz)	Gp	_	6.5	_	dB
Collector Efficiency (V _{CC} = 26 V, P _{out} = 25 W, f = 1.88 GHz)	η	38	43	_	%

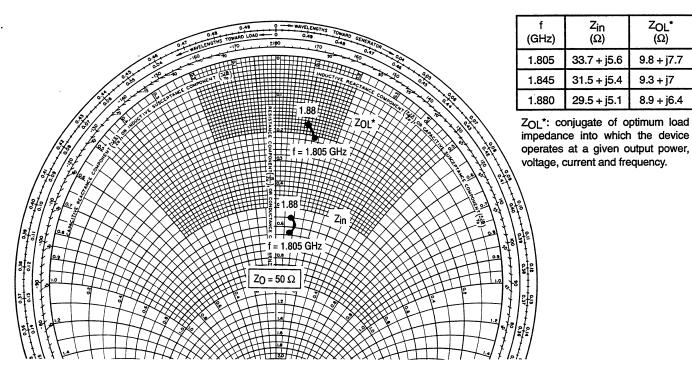


Figure 1. Series Equivalent Input and Output Impedances

TYPICAL CHARACTERISTICS

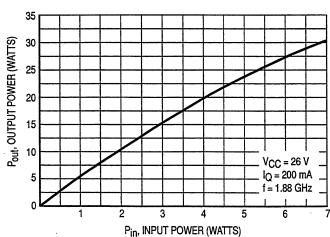


Figure 2. Output Power versus Input Power

Z_{OL}* (Ω)

9.8 + j7.79.3 + j7

8.9 + j6.4

Z_{in} (Ω)

33.7 + j5.6

31.5 + j5.429.5 + j5.1

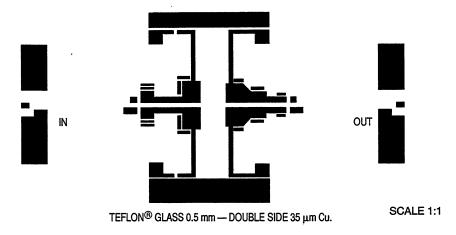


Figure 3. Photomaster

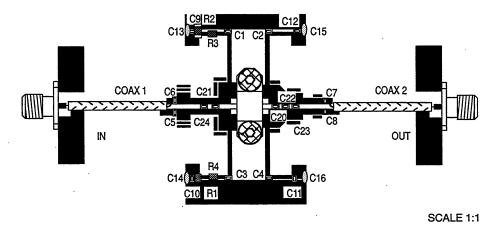
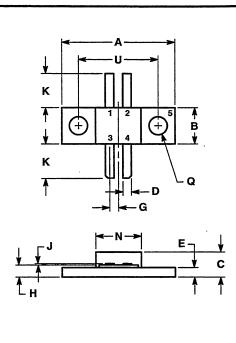


Figure 4. Components View

C1 to C8	68 pF, ATC Chip Capacitor 100A
C9 to C12	330 pF, Chip Capacitor 0805
C13 to C16	4.7 μF, 35 V, Capacitor
C20	1.3 pF, ATC Chip Capacitor 100A
C21 to C23	1 pF, ATC Chip Capacitor 100A
C24	0.5 pF, ATC Chip Capacitor 100A
R1, R2	56 Ω, Chip Resistor 1206
R3, R4	2.2 Ω, Chip Resistor 0805
Coax 1, Coax 2	50Ω Coaxial, $I = 27 \text{ mm}$

OUTLINE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.795	0.805	20.19	20.45
В	0.255	0.265	6.48	6.73
C	0.161	0.189	4.09	4.80
D	0.055	0.065	1.40	1.65
Е	0.055	0.065	1.40	1.65
G	0.055	0.065	1.40	1.65
Н	0.075	0.095	1.90	2.41
J	0.003	0.006	0.08	0.15
K	0.170	0.220	4.32	5.59
N	0.260	0.266	6.60	6.76
Q	0.125	0.135	3.18	3.42
U	0.552	0.572	14.03	14.52

STYLE 1: PIN 1. BASE

- 2. BASE 3. COLLECTOR
- 4. COLLECTOR 5. EMITTER

CASE 395-02

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